

Features

- · AEC-Q101 Qualified
- Trench MV MOSFET Technology
- Halogen Free. "Green" Device (Note1)
- · Moisture Sensitivity Level 1
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-Channel MOSFET

Maximum Ratings

Operating Junction Temperature Range: -55°C to +150°C

Storage Temperature: -55°C to +150°C

Thermal Resistance: 350°C/W Junction to Ambient^(Note2)

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Volltage		V _{GS}	±10	V	
Continuous Drain Current	T _A =25°C	ı	2	Α	
	T _A =70°C	- I _D	1.6		
Pulsed Drain Current (Note 3)		I _{DM}	8	Α	
Total Power Dissipation ^(Note4)		P _D	357	mW	

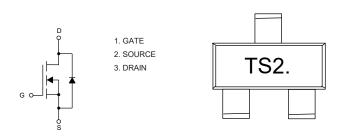
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

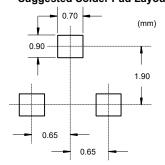
SOT-323

DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.071	0.087	1.80	2.20		
В	0.045	0.053	1.15	1.35		
С	0.083	0.096	2.10	2.45		
D	0.026		0.65		TYP.	
Е	0.047	0.055	1.20	1.40		
F	0.012	0.016	0.30	0.40		
G	0.000	0.004	0.00	0.10		
Н	0.035	0.044	0.90	1.10		
J	0.002	0.010	0.05	0.25		
K	0.006	0.016	0.15	0.40		
L	0.010	0.018	0.26	0.46		

Internal Structure and Marking Code



Suggested Solder Pad Layout





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics					1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	20			V	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.5	0.8	1.1	V	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA	
Drain Source On Registence	R	V _{GS} =4.5V, I _D =2.5A		60	80	mΩ	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =2.5V, I _D =2A		75	98		
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =1.5A		7.5		S	
Gate Resistance	R _g	f=1 MHz, Open drain		1.8		Ω	
Diode Characteristics			'				
Continuous Body Diode Current	Is				2	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =2.5A			1.2	V	
Reverse Recovery Time	t _{rr}	- I _F =2A, dI _F /dt=80A/μs		5		ns	
Reverse Recovery Charge	Q _{rr}	- I _F -2A, αι _F /αι-ουΑ/μ5		1		nC	
Dynamic Characteristics			·				
Input Capacitance	C _{iss}			210			
Output Capacitance	C _{oss}	V _{DS} =10V,V _{GS} =0V,f=1MHz		36		pF	
Reverse Transfer Capacitance	C _{rss}			29			
Total Gate Charge	Q _g			3.2			
Gate-Source Charge	Q _{gs}	V _{DS} =10V,V _{GS} =4.5V,I _D =2A		0.8		nC	
Gate-Drain Charge	Q_{gd}			0.8			
Turn-On Delay Time	t _{d(on)}			5			
Turn-On Rise Time	t _r	$V_{DD} = 10 \text{V}, V_{GS} = 4.5 \text{V},$		28			
Turn-Off Delay Time	t _{d(off)}	$R_G=3\Omega$, $I_D=2A$		15		ns	
Turn-Off Fall Time	t _f			28			



Curve Characteristics

50

0

1

1.5

Fig.1 - Typical Output Characteristics

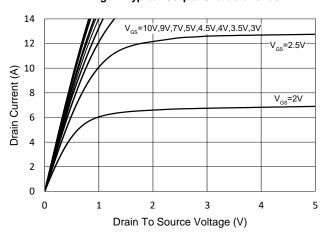
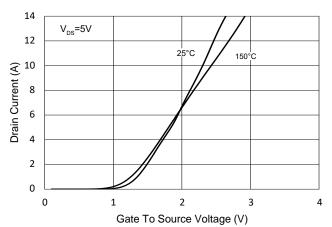


Fig.2 - Transfer Characteristic

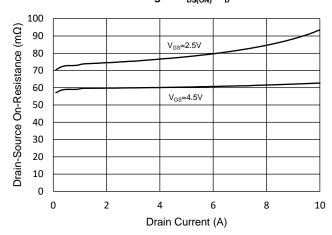


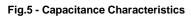
350 Drain-Source On-Resistance (mΩ) I_D=2.5A 300 250 200 150 25℃ 100

2.5

Fig.3 - R_{DS(ON)} - V_{GS}

Fig.4 - $R_{DS(ON)}$ - I_D





Gate To Source Voltage (V)

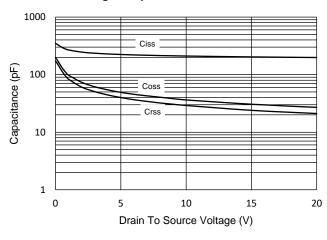
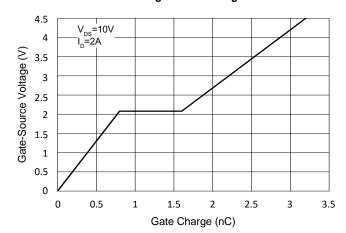


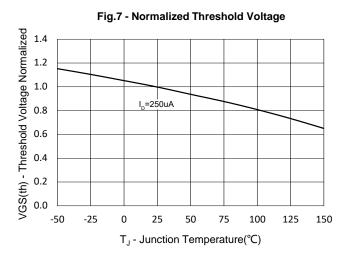
Fig.6 - Gate Charge

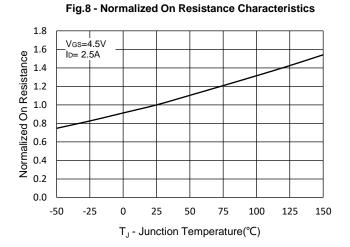


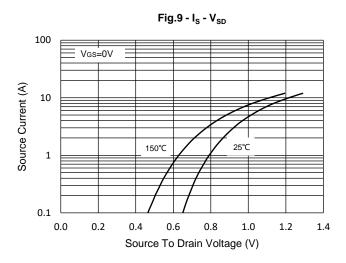
4.5

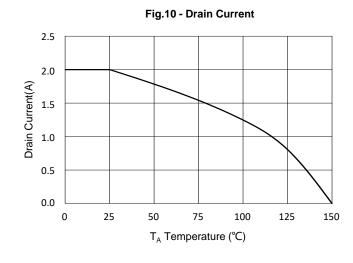


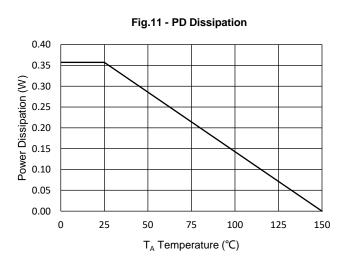
Curve Characteristics





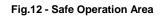








Curve Characteristics



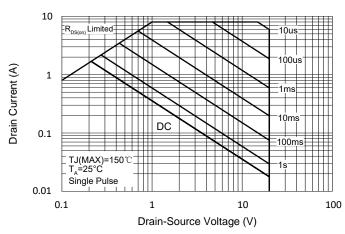
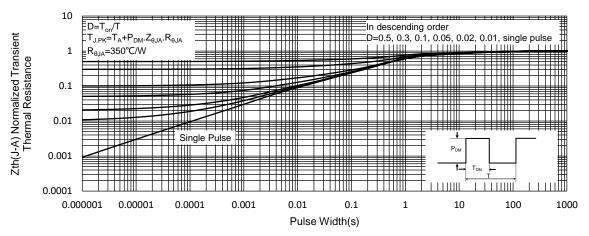


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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